

REVISIONS

LTR	DESCRIPTION													DATE (YR-MO-DA)			APPROVED

REV																							
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SHEET	15	16	17	18	19	21	21	22	23	24	25	26	27										
REV STATUS OF SHEETS				REV																			
				SHEET				1	2	3	4	5	6	7	8	9	10	11	12	13	14		
PMIC N/A				PREPARED BY Kenneth Rice				DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444															
STANDARDIZED MILITARY DRAWING THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE AMSC N/A				CHECKED BY Rajesh Pithadia				MICROCIRCUIT, MEMORY, DIGITAL, CMOS, UV ERASABLE PROGRAMMABLE, LOGIC DEVICE, MONOLITHIC SILICON															
				APPROVED BY Michael Frye																			
				DRAWING APPROVAL DATE 93-10-18				SIZE A	CAGE CODE 67268	5962-93144													
				REVISION LEVEL				SHEET		1	OF		27										

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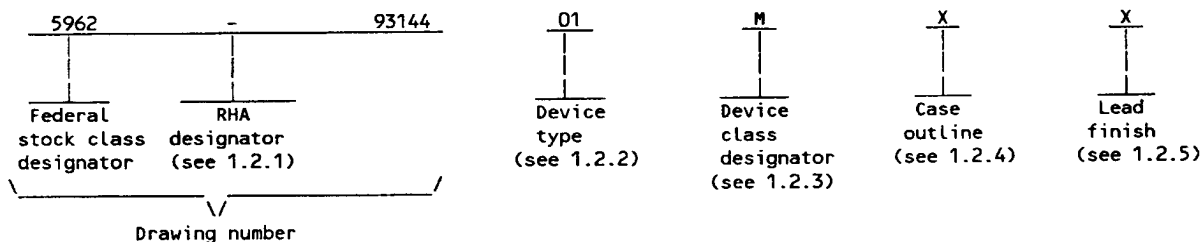
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5962-E375-93

1. SCOPE

1.1 Scope. This drawing forms a part of a one part - one part number documentation system (see 6.6 herein). Two product assurance classes consisting of military high reliability (device classes B, Q, and M) and space application (device classes S and V) and a choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). Device class M microcircuits represent non-JAN class B microcircuits in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices". When available, a choice of radiation hardness assurance (RHA) levels are reflected in the PIN.

1.2 PIN. The PIN shall be as shown in the following example:



1.2.1 RHA designator. Device classes M, B, and S RHA marked devices shall meet the MIL-M-38510 specified RHA levels and shall be marked with the appropriate RHA designator. Device classes Q and V RHA marked devices shall meet the MIL-I-38535 specified RHA levels and shall be marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.

1.2.2 Device types. The device types shall identify the circuit function as follows:

Device type	Generic number 1/	Circuit function	Propagation delay time
01		128 Macrocell EPLD	35 ns
02		128 Macrocell EPLD	30 ns

1.2.3 Device class designator. The device class designator shall be a single letter identifying the product assurance level as follows:

Device class	Device requirements documentation
M	Vendor self-certification to the requirements for non-JAN class B microcircuits in accordance with 1.2.1 of MIL-STD-883
B or S	Certification and qualification to MIL-M-38510
Q or V	Certification and qualification to MIL-I-38535

1.2.4 Case outlines. The case outlines shall be as designated in MIL-STD-1835, and as follows:

Outline letter	Descriptive designator	Terminals	Package style
X	see figure 1	100	Quad flat package 2/
Y	CMGA5-P100E	100	Pin grid array 2/ 3/
Z	CMGA17-P100E	100	Pin grid array 2/ 3/
U	GQCC1-J84	84	J leaded chip carrier 2/

1.2.5 Lead finish. The lead finish shall be as specified in MIL-M-38510 for classes M, B, and S or MIL-I-38535 for classes Q and V. Finish letter "X" shall not be marked on the microcircuit or its packaging. The "X" designation is for use in specifications when lead finishes A, B, and C are considered acceptable and interchangeable without preference.

1/ Generic numbers are listed on the Standardized Military Drawing Source Approval Bulletin at the end of this document and will also be listed in MIL-BUL-103.
 2/ Lid shall be transparent to permit ultraviolet light erasure.
 3/ 100 = actual number of pins used, not maximum listed in MIL-STD-1835

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1.3 Absolute maximum ratings. 3/

Supply voltage range (V_{CC})	- - - - -	-2.0 V dc to +7.0 V dc
Programming supply voltage range (V_{PP})	- - - - -	-2.0 V dc to +13.5 V dc <u>4/</u>
DC input voltage range	- - - - -	-2.0 V dc to +7.0 V dc <u>4/</u>
Maximum power dissipation	- - - - -	2.5 W <u>5/</u>
Lead temperature (soldering, 10 seconds)	- - - - -	+260°C
Thermal resistance, junction-to-case (θ_{JC}):		
Case outlines X and Y	- - - - -	See MIL-STD-1835
Junction temperature (T_J)	- - - - -	+175°C
Storage temperature range	- - - - -	-65°C to +150°C
Temperature under bias range	- - - - -	-55°C to +125°C
Endurance	- - - - -	25 erase/write cycles (minimum)
Data retention	- - - - -	10 years (minimum)

1.4 Recommended operating conditions.

Supply voltage range (V_{CC})	- - - - -	+4.5 V dc to +5.5 V dc
Ground voltage (GND)	- - - - -	0 V dc
Input high voltage (V_{IH})	- - - - -	2.2 V dc minimum
Input low voltage (V_{IL})	- - - - -	0.8 V dc maximum
Case operating temperature range (T_C)	- - - - -	-55°C to +125°C <u>6/</u>
Input rise time (t_R)	- - - - -	100 ns maximum
Input fall time (t_F)	- - - - -	100 ns maximum

1.5 Digital logic testing for device classes Q or V.

Fault coverage measurement of manufacturing logic tests (MIL-STD-883, test method 5012) - - - - - 7/ percent

2. APPLICABLE DOCUMENTS

2.1 Government specifications, standards, bulletin, and handbook. Unless otherwise specified, the following specifications, standards, bulletin, and handbook of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATIONS

MILITARY

- MIL-M-38510 - Microcircuits, General Specification for.
- MIL-I-38535 - Integrated Circuits, Manufacturing, General Specification for.

STANDARDS

MILITARY

- MIL-STD-480 - Configuration Control-Engineering Changes, Deviations and Waivers.
- MIL-STD-883 - Test Methods and Procedures for Microelectronics.
- MIL-STD-1835 - Microcircuit Case Outlines.

- 3/ Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.
- 4/ Minimum dc input voltage is -0.5 V. During transitions, inputs may undershoot to -2.0 V for periods less than 20 ns. Maximum dc voltage on output pins is $V_{CC} + 0.5$ V, which may overshoot to +7.0 V for periods less than 20 ns under no load conditions.
- 5/ Must withstand the added P_D due to short circuit test (e.g., I_{OS}).
- 6/ Case temperatures are instant on.
- 7/ Values will be added when they become available.

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BULLETIN

MILITARY

MIL-BUL-103 - List of Standardized Military Drawings (SMD's).

HANDBOOK

MILITARY

MIL-HDBK-780 - Standardized Military Drawings.

(Copies of the specifications, standards, bulletin, and handbook required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 Non-Government publications. The following document(s) form a part of this document to the extent specified herein. Unless otherwise specified, the issues of the documents which are DoD adopted are those listed in the issue of the DODISS cited in the solicitation. Unless otherwise specified, the issues of documents not listed in the DODISS are the issues of the documents cited in the solicitation.

AMERICAN SOCIETY FOR TESTING AND MATERIALS (ASTM)

ASTM Standard F1192-88 - Standard Guide for the Measurement of Single Event Phenomena from Heavy Ion Irradiation of Semiconductor Devices.

(Applications for copies of ASTM publications should be addressed to the American Society for Testing and Materials, 1916 Race Street, Philadelphia, PA 19103.)

ELECTRONICS INDUSTRIES ASSOCIATION (EIA)

JEDEC Standard No. 17 - A Standardized Test Procedure for the Characterization of Latch-up in CMOS Integrated Circuits.

(Applications for copies should be addressed to the Electronics Industries Association, 2001 Pennsylvania Street, N.W., Washington, DC 20006.)

(Non-Government standards and other publications are normally available from the organizations that prepare or distribute the documents. These documents also may be available in or through libraries or other informational services.)

2.3 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

3.1 Item requirements. The individual item requirements for device class M shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein. The individual item requirements for device classes B and S shall be in accordance with MIL-M-38510 and as specified herein. For device classes B and S, a full electrical characterization table for each device type shall be included in this SMD. The individual item requirements for device classes Q and V shall be in accordance with MIL-I-38535, the device manufacturer's Quality Management (QM) plan, and as specified herein.

3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 for device classes M, B, and S and MIL-I-38535 for device classes Q and V and herein.

3.2.1 Case outlines. The case outlines shall be in accordance with 1.2.4 herein and figure 1.

3.2.2 Terminal connections. The terminal connections shall be as specified on figure 2.

3.2.3 Radiation exposure circuit. The radiation exposure circuit will be provided when RHA product becomes available.

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3.2.4 Truth tables. The truth tables shall be as specified on figure 3.

3.2.4.1 Unprogrammed devices. The truth table for unprogrammed devices for contracts involving no altered item drawing shall be as specified on figure 2. When required in screening (see 4.2 herein), or qualification conformance inspection groups A, B, C, or D (see 4.3 herein), the devices shall be programmed by the manufacturer prior to test. A minimum of 50 percent of the total number of gates shall be programmed or at least 25 percent of the total number of gates to any altered item drawing.

3.2.4.2 Programmed devices. The truth table for programmed devices shall be as specified by an attached altered item drawing.

3.3 Electrical performance characteristics and post irradiation parameter limits. Unless otherwise specified herein, the electrical performance characteristics and post irradiation parameter limits are as specified in table I and shall apply over the full case operating temperature range.

3.4 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table IIA. The electrical tests for each subgroup are defined in table I.

3.5 Marking. The part shall be marked with the PIN listed in 1.2 herein. Marking for device class M shall be in accordance with MIL-STD-883 (see 3.1 herein). In addition, the manufacturer's PIN may also be marked as listed in MIL-BUL-103. Marking for device classes B and S shall be in accordance with MIL-M-38510. Marking for device classes Q and V shall be in accordance with MIL-I-38535.

3.5.1 Certification/compliance mark. The compliance mark for device class M shall be a "C" as required in MIL-STD-883 (see 3.1 herein). The certification mark for device classes B and S shall be a "J" or "JAN" as required in MIL-M-38510. The certification mark for device classes Q and V shall be a "QML" as required in MIL-I-38535.

3.6 Certificate of compliance. For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-BUL-103 (see 6.7.3 herein). For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.7.2 herein). The certificate of compliance submitted to DESC-EC prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device class M, the requirements of MIL-STD-883 (see 3.1 herein), or for device classes Q and V, the requirements of MIL-I-38535 and the requirements herein.

3.7 Certificate of conformance. A certificate of conformance as required for device class M in MIL-STD-883 (see 3.1 herein) or device classes B and S in MIL-M-38510 or for device classes Q and V in MIL-I-38535 shall be provided with each lot of microcircuits delivered to this drawing.

3.8 Notification of change for device class M. For device class M notification to DESC-EC of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change as defined in MIL-STD-480.

3.9 Verification and review for device class M. For device class M, DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.

3.10 Microcircuit group assignment for device classes M, B, and S. Device classes M, B, and S devices covered by this drawing shall be in microcircuit group number 42 (see MIL-M-38510, appendix E).

3.11 Serialization for device class S and V. All device class S devices shall be serialized in accordance with MIL-M-38510. Class V shall be serialized in accordance with MIL-I-38535.

3.12 Processing EPLDs. All testing requirements and quality assurance provisions herein shall be satisfied by the manufacturer prior to delivery.

3.12.1 Erase of EPLDs. When specified, devices shall be erased in accordance with the procedures and characteristics specified in 4.6.

3.12.2 Programmability of EPLDs. When specified, devices shall be programmed to the specified pattern using the procedures and characteristics specified in 4.5.

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TABLE I. Electrical performance characteristics.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified	Group A subgroups	Device type	Limit		Unit	
					Min	Max		
Output high voltage	V _{OH}	V _{CC} = 4.5 V, I _{OH} = -4 mA V _{IH} = 2.2 V, V _{IL} = 0.8 V	1,2,3	All	2.4		V	
Output low voltage	V _{OL}	V _{CC} = 4.5 V, I _{OL} = 8 mA V _{IH} = 2.2 V, V _{IL} = 0.8 V				0.45		
Input high voltage <u>1/ 2/</u>	V _{IH}				2.2			
Input low voltage <u>1/ 2/</u>	V _{IL}					0.8		
Input leakage current	I _{IX}	V _{CC} = 5.5 V, V _{IN} = 5.5 V and GND			-10	+10		μA
Output leakage current	I _{OZ}	V _{CC} = 5.5 V, V _{IN} = 5.5 V and GND	-40		+40			
Output short circuit current <u>3/ 4/</u>	I _{OS}	V _{CC} = 5.5 V, V _{OUT} = 0.5 V	-30		-90	mA		
Power supply current <u>4/ 5/</u>	I _{CC1}	V _{CC} = 5.5 V, I _{OUT} = 0 mA, V _{IN} = V _{CC} or GND f = 1.0 MHz			375			
Power supply current (standby)	I _{CC2}	V _{CC} = 5.5 V, I _{OUT} = 0 mA, V _{IN} = V _{CC} or GND,			325			
Input capacitance <u>2/</u>	C _{IN}	V _{CC} = 5.0 V, T _A = +25°C, f = 1 MHz, (see 4.4.1f)	4			10	pF	
Output capacitance <u>2/</u>	C _{OUT}	V _{CC} = 5.0 V, T _A = +25°C, f = 1 MHz, (see 4.4.1f)	4		20			
Functional testing		See 4.4.1c	7,8A,8B					

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified	Group A subgroups	Device type	Limit		Unit
					Min	Max	
Dedicated input to combinatorial output delay <u>7/</u>	t _{PD1}	See figures 4 (circuit A) and 5 <u>6/</u>	9,10,11	01		35	ns
				02		30	
I/O input to combinatorial output delay <u>8/</u>	t _{PD2}			01		55	
				02		45	
Dedicated input to combinatorial output delay with expander delay <u>9/</u>	t _{PD3}			01		55	
				02		44	
I/O input to combinatorial output delay with expander delay <u>2/ 4/ 10/</u>	t _{PD4}			01		75	
				02		59	
Input to output enable delay <u>4/ 7/</u>	t _{EA}			01		35	
				02		30	
Input to output disable delay <u>4/ 7/</u>	t _{ER}	01		35			
		02		30			
Synchronous clock input to output delay	t _{CO1}	01		20			
		02		16			
Synchronous clock to local feedback to combinatorial output <u>4/ 11/</u>	t _{CO2}	01		42			
		02		35			

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified	Group A subgroups	Device type	Limit		Unit
					Min	Max	
Dedicated input or feedback setup time to synchronous clock input <u>7/ 12/</u>	t _{S1}	See figures 4 (circuit A) and 5 <u>6/</u>	9,10,11	01	25		ns
				02	20		
I/O input setup time to synchronous clock input <u>7/ 12/</u>	t _{S2}			01	45		
				02	36		
Input hold time from synchronous clock input <u>7/</u>	t _H			All	0		
Synchronous clock input high time <u>2/</u>	t _{WH}			01	12.5		
				02	10		
Synchronous clock input low time <u>2/</u>	t _{WL}			01	12.5		
				02	10		
Asynchronous clear width <u>2/ 4/ 7/</u>	t _{RW}			01	35		
				02	30		
Asynchronous clear recovery time <u>2/ 4/ 7/</u>	t _{RR}			01	35		
				02	30		
Asynchronous clear to registered output delay <u>2/ 7/</u>	t _{RO}			01		35	
		02		30			

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - continued

Test	Symbol	Conditions -55°C ≤ T _c ≤ +125°C 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified	Group A subgroups	Device type	Limit		Unit
					Min	Max	
Asynchronous preset width 2/ 4/ 7/	t _{PW}	See figures 4 (circuit A) and 5 6/	9,10,11	01	35		ns
				02	30		
Asynchronous preset recovery time 2/ 4/ 7/	t _{PR}			01	35		
				02	30		
Asynchronous preset to registered output delay 2/ 7/	t _{PO}			01		35	
				02		30	
Synchronous clock to local feedback input 4/ 13/	t _{CF}			01		6	
				02		3	
External synchronous clock period (1/f _{MAX3}) 4/	t _p			01	25		
				02	20		
External feedback maximum frequency (1/(t _{CO1} + t _{S1})) 4/ 14/	f _{MAX1}	01	22.2		MHz		
		02	27.7				
Internal local feedback maximum frequency, lesser of (1/(t _{S1} + t _{CF})) or (1/t _{CO1}) 4/ 15/	f _{MAX2}	01	32.2				
		02	43.6				
Data path maximum frequency, least of 1/(t _{WL} + t _{WH}), 1/(t _{S1} + t _H) or (1/t _{CO1}) 4/ 16/	f _{MAX3}	01	40				
		02	50				

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified	Group A subgroups	Device type	Limit		Unit
					Min	Max	
Maximum register toggle frequency (1/(t _{WL} + t _{WH})) 4/ 17/	f _{MAX4}	See figures 4 (circuit A) and 5 6/	9,10,11	01	40		MHz
				02	50		
Output data stable time from synchronous clock input 4/ 18/	t _{OH}			ALL	3		ns
External asynchronous switching characteristics							
Dedicated asynchronous clock input to output delay 6/	t _{AC01}	See figures 4 (circuit A) and 5 6/	9,10,11	01		35	ns
				02		30	
Asynchronous clock input to local feedback to combinatorial output 2/ 19/	t _{AC02}			01		55	
				02		46	
Dedicated input or feedback setup time to asynchronous clock input 6/	t _{AS1}			01	8		
				02	6		
I/O input setup time to asynchronous clock input 4/ 6/	t _{AS2}			01	28		
				02	22		
Input hold time from asynchronous clock input 6/	t _{AH}			01	10		
				02	8		
Asynchronous clock input high time 2/ 6/	t _{AWH}			01	16		
				02	14		

See footnotes at end of table.

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TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions -55°C ≤ T _C ≤ +125°C 4.5 V ≤ V _{CC} ≤ 5.5 V unless otherwise specified	Group A subgroups	Device type	Limit		Unit		
					Min	Max			
Asynchronous clock input low time <u>2/ 7/ 20/</u>	t _{AWL}	See figures 4 (circuit A) and 5 <u>6/</u>	9,10,11	01	14		ns		
				02	11				
Asynchronous clock to local feedback input <u>4/ 21/</u>	t _{ACF}			01		22			
				02		18			
External asynchronous clock period (1/f _{MAXA4}) <u>4/</u>	t _{AP}					01	30		
						02	25		
External feedback maximum frequency in asynchronous mode 1/(t _{AC01} + t _{AS1}) <u>4/ 22/</u>	f _{MAXA1}					01	23		MHz
						02	27		
Maximum internal asynchronous frequency <u>4/ 23/</u>	f _{MAXA2}					01	33.3		
						02	40		
Data path maximum frequency in asynchronous mode <u>4/ 24/</u>	f _{MAXA3}			01	28.5				
				02	33.3				
Maximum asynchronous register toggle frequency 1/(t _{AWH} + t _{AWL}) <u>4/ 25/</u>	f _{MAXA4}			01	33.3				
				02	40				
Output data stable time from asynchronous clock input <u>4/ 26/</u>	t _{AOH}			ALL	15		ns		

- 1/ These are absolute values with respect to device ground and all overshoots due to system or tester noise are included.
- 2/ Tested initially and after any design or process changes that affect that parameter, and therefore shall be guaranteed to the limits specified in table I.
- 3/ For test purposes, not more than one output at a time should be shorted. Short circuit test duration should not exceed 1 second.
- 4/ May not be tested but shall be guaranteed to the limits specified in table I.
- 5/ Measured with device programmed as a 16-bit counter in each LAB.
- 6/ AC tests are performed with input rise and fall times of 6 ns or less, timing reference levels of 1.5 V, input pulse levels of 0 to 3.0 V, and the output loads on figure 4.
- 7/ This specification is a measure of the delay from input signal applied to a dedicated input to combinatorial output on any output pin. This delay assumes no expander terms are used to form the logic function.

When this note is applied to any parameter specification it indicates that the signal (data, asynchronous clock, asynchronous clear, and/or asynchronous preset) is applied to a dedicated input only and no signal path (either clock or data) employs expander logic.

If an input signal is applied to an I/O pin, an additional delay equal to t_{pIA} should be added to the comparable delay for a dedicated input. If expanders are used, add the maximum expander delay t_{EXP} to the overall delay for the comparable delay without expanders.

- 8/ This specification is a measure of the delay from input signal applied to an I/O macrocell pin to any output. This delay assumes no expander terms are used to form the logic function.
- 9/ This specification is a measure of the delay from an input signal applied to a dedicated input to combinatorial output on any output pin. This delay assumes expander terms are used to form the logic function and includes the worst-case expander logic delay for one pass through the expander logic.

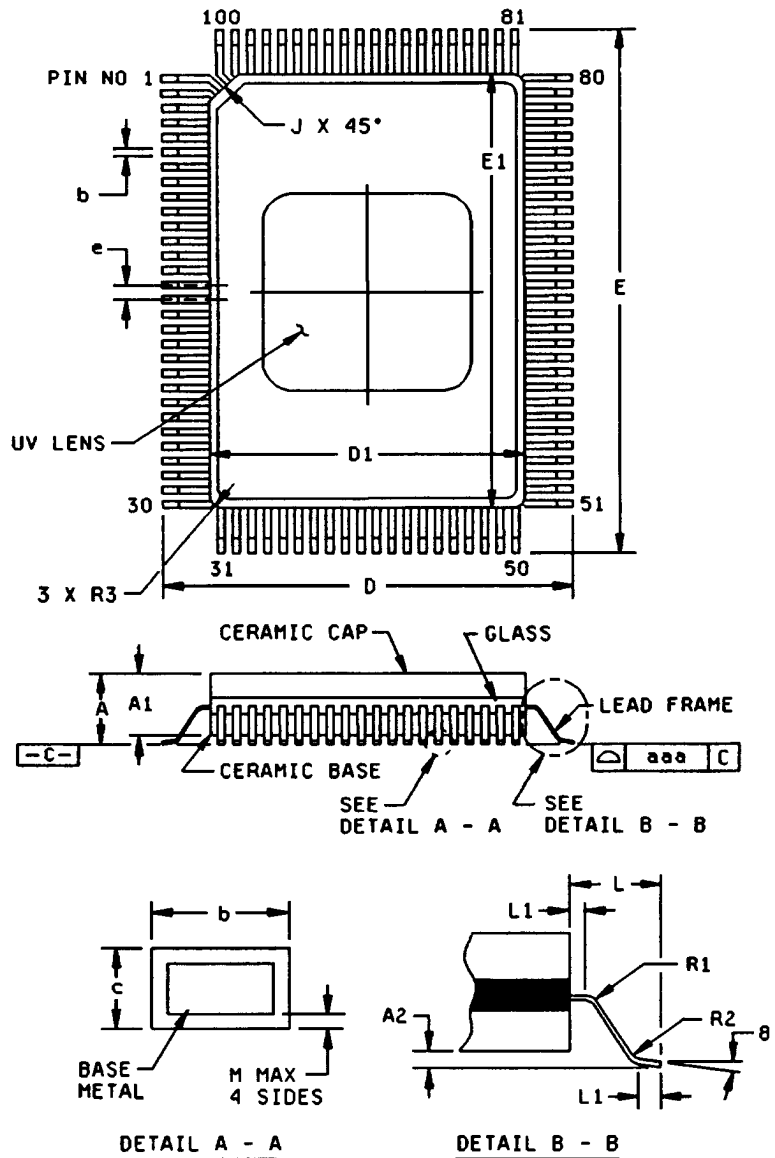
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TABLE I. Electrical performance characteristics - Continued.

- 10/ This specification is a measure of the delay from an input signal applied to an I/O macrocell pin to any output. This delay assumes expander terms are used to form the logic function and includes the worst-case expander logic delay for one pass through the expander logic.
- 11/ This specification is a measure of the delay from synchronous register clock to internal feedback of the register output signal to the input of the LAB logic array and then to a combinatorial output. This delay assumes no expanders are used, register is synchronously clocked and all feedback is within the same LAB.
- 12/ If data is applied to an I/O input for capture by a macrocell register, the I/O pin set-up time minimums should be observed. These parameters are t_{S2} for synchronous operation and t_{AS2} for asynchronous operation.
- 13/ This specification is a measure of the delay associated with the internal register feedback path. This is the delay from synchronous clock to LAB logic array input. This delay plus the register set-up time, t_{S1} , is the minimum internal period for an internal synchronous state machine configuration. This delay is for feedback within the same LAB.
- 14/ This specification indicates the guaranteed maximum frequency, in synchronous mode, at which a state machine configuration with external feedback can operate. It is assumed that all data inputs and feedback signals are applied to dedicated inputs. All feedback is assumed to be local, originating within the same LAB.
- 15/ This specification indicates the guaranteed maximum frequency at which a state machine, with internal-only feedback, can operate. If register output states must also control external points, this frequency can still be observed as long as this frequency is less than $1/t_{CO1}$.
- 16/ This frequency indicates the maximum frequency at which the device may operate in data path mode. This delay assumes data input signals are applied to dedicated inputs and no expander logic is used. If any of the data inputs are I/O pins, t_{S2} is the appropriate t_S for calculation.
- 17/ This specification indicates the guaranteed maximum frequency, in synchronous mode, at which an individual output or buried register can be cycled by a clock signal applied to the dedicated clock input pin.
- 18/ This parameter indicates the minimum time after a synchronous register clock input that the previous register output data is maintained on the output pin.
- 19/ This specification is a measure of the delay from an asynchronous register clock input to internal feedback of the register output signal to the input of the LAB logic array and then to a combinatorial output. This delay assumes no expanders are used in the logic of combinatorial output or the asynchronous clock input. The clock signal is applied to a dedicated input pin and all feedback is within a single LAB.
- 20/ This parameter is measured with a positive-edge triggered clock at the register. For negative edge triggering, the t_{AWH} and t_{AWL} parameters must be swapped. If a given input is used to clock multiple registers with both positive and negative polarity, t_{AWH} should be used for both t_{AWH} and t_{AWL} .
- 21/ This specification is a measure of the delay associated with the internal register feedback path for an asynchronous clock to LAB logic array input. This delay plus the asynchronous register set-up time, t_{AS1} , is the minimum internal period for an internal asynchronous clocked state machine configuration. This delay is for feedback within the same LAB, assumes no expander logic in the clock path, and assumes that the clock input signal is applied to a dedicated input pin.
- 22/ This specification indicates the guaranteed maximum frequency at which an asynchronously clocked state machine configuration with external feedback can operate. It is assumed that all data inputs, clock inputs, and feedback signals are applied to dedicated inputs, and that no expander logic is employed in the clock signal path or data path.
- 23/ This specification indicates the guaranteed maximum frequency at which an asynchronously clocked state machine with internal-only feedback can operate. This parameter is determined by the lesser of $(1/(t_{ACF} + 1/t_{AS1}))$ or $(1/(t_{AWH} + t_{AWL}))$. If register output states must also control external points, this frequency can still be observed as long as this frequency is less than $1/t_{ACO1}$.
- 24/ This frequency is the maximum frequency at which the device may operate in the asynchronously clocked data path mode. This specification is determined by the least of $1/(t_{AWH} + t_{AWL})$, $1/(t_{AS1} + t_{AH})$ or $1/t_{ACO1}$. It assumes data and clock input signals are applied to dedicated input pins and no expander logic is used.
- 25/ This specification indicates the guaranteed maximum frequency at which an individual output or buried register can be cycled in asynchronously clocked mode by a clock signal applied to an external dedicated input pin.
- 26/ This parameter indicates the minimum time that the previous register output data is maintained on the output after an asynchronous register clock input applied to an external dedicated input pin.

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Note: See dimension chart and notes on next page.

FIGURE 1. Case outline.

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Symbol	Metric (mm)
aaa	0.10 max
A	2.85± .5
A1	2.45± .3
A2	.40± 0.20
b	.030 max
c	.009± .02
D	17.20± 0.20
D1	13.20± 0.13
E	23.20± 0.20
E1	19.20± 0.18
e	0.65 max
J	1.20 max
L	2.0± 0.20
L1	0.58± 0.20
L2	0.52± 0.20
M	0.04 max
R1	0.30 max
R2	0.30 max
R3	0.50 max
non measured values	
ND/NE	60/40
N	100

Notes: ND and NE represent number of terminals on a side, while N represents the total number of terminals on the package.

FIGURE 1. Case outline - Continued.

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Case outline X

Device types	All	Device types	All	Device types	All
Terminal number	Terminal symbol	Terminal number	Terminal symbol	Terminal number	Terminal symbol
1	I/O	35	I/O	68	VCC
2	I/O	36	I/O	69	VCC
3	I/O	37	GND	70	INPUT
4	I/O	38	GND	71	INPUT
5	I/O	39	I/O	72	INPUT
6	I/O	40	I/O	73	I/O
7	I/O	41	I/O	74	I/O
8	I/O	42	I/O	75	I/O
9	INPUT	43	VCC	76	I/O
10	INPUT	44	VCC	77	I/O
11	INPUT	45	I/O	78	I/O
12	GND	46	I/O	79	I/O
13	GND	47	I/O	80	I/O
14	INPUT	48	I/O	81	I/O
15	INPUT	49	I/O	82	I/O
16	INPUT/CLK	50	I/O	83	I/O
17	INPUT	51	I/O	84	I/O
18	VCC	52	I/O	85	I/O
19	VCC	53	I/O	86	I/O
20	INPUT	54	I/O	87	GND
21	INPUT	55	I/O	88	GND
22	INPUT	56	I/O	89	I/O
23	I/O	57	I/O	90	I/O
24	VCC	58	I/O	91	I/O
25	I/O	59	INPUT	92	I/O
26	I/O	60	INPUT	93	VCC
27	I/O	61	INPUT	94	VCC
28	I/O	62	GND	95	I/O
29	I/O	63	GND	96	I/O
30	I/O	64	INPUT	97	I/O
31	I/O	65	INPUT	98	I/O
32	I/O	66	INPUT	99	I/O
33	I/O	67	INPUT	100	I/O
34	I/O				

FIGURE 2. Terminal connections.

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Case outline Y AND Z

Device types	All	Device types	All	Device types	All
Terminal number	Terminal symbol	Terminal number	Terminal symbol	Terminal number	Terminal symbol
A1	I/O	D1	I/O	K13	I/O
A2	I/O	D2	I/O	L1	I/O
A3	I/O	D12	I/O	L2	I/O
A4	I/O	D13	I/O	L6	GND
A5	Input	E1	I/O	L7	INPUT
A6	VCC	E2	I/O	L8	INPUT
A7	INPUT	E12	I/O	L12	I/O
A8	INPUT	E13	I/O	L13	I/O
A9	INPUT	F1	I/O	M1	I/O
A10	INPUT	F2	GND	M2	I/O
A11	I/O	F3	GND	M3	I/O
A12	I/O	F11	I/O	M4	I/O
A13	I/O	F12	VCC	M5	INPUT
B1	I/O	F13	VCC	M6	GND
B2	I/O	G1	I/O	M7	INPUT
B3	I/O	G2	I/O	M8	VCC
B4	I/O	G3	I/O	M9	INPUT
B5	INPUT	G11	I/O	M10	I/O
B6	VCC	G12	I/O	M11	I/O
B7	INPUT	G13	I/O	M12	I/O
B8	GND	H1	VCC	M13	I/O
B9	INPUT	H2	VCC	N1	I/O
B10	I/O	H3	I/O	N2	I/O
B11	I/O	H11	GND	N3	I/O
B12	I/O	H12	GND	N4	INPUT
B13	I/O	H13	I/O	N5	INPUT
C1	I/O	J1	I/O	N6	INPUT
C2	I/O	J2	I/O	N7	INPUT
C6	INPUT	J12	I/O	N8	VCC
C7	INPUT/CLK	J13	I/O	N9	INPUT
C8	GND	K1	I/O	N10	I/O
C12	I/O	K2	I/O	N11	I/O
C13	I/O	K12	I/O	N12	I/O
				N13	I/O

FIGURE 2. Terminal connections - Continued.

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Case outline U

Device types	All	Device types	All	Device types	All
Terminal number	Terminal symbol	Terminal number	Terminal symbol	Terminal number	Terminal symbol
1	INPUT/CLK	35	I/O	68	I/O
2	INPUT	36	INPUT	69	I/O
3	VCC	37	INPUT	70	I/O
4	VCC	38	INPUT	71	I/O
5	INPUT	39	GND	72	I/O
6	INPUT	40	GND	73	I/O
7	INPUT	41	INPUT	74	I/O
8	I/O	42	INPUT	75	I/O
9	I/O	43	INPUT	76	I/O
10	I/O	44	INPUT	77	I/O
11	I/O	45	VCC	78	INPUT
12	I/O	46	VCC	79	INPUT
13	I/O	47	INPUT	80	INPUT
14	I/O	48	INPUT	81	GND
15	I/O	49	INPUT	82	GND
16	I/O	50	I/O	83	INPUT
17	I/O	51	I/O	84	INPUT
18	I/O	52	I/O		
19	GND	53	I/O		
20	GND	54	I/O		
21	I/O	55	I/O		
22	I/O	56	I/O		
23	VCC	57	I/O		
24	VCC	58	I/O		
25	I/O	59	I/O		
26	I/O	60	I/O		
27	I/O	61	GND		
28	I/O	62	GND		
29	I/O	63	I/O		
30	I/O	64	I/O		
31	I/O	65	VCC		
32	I/O	66	VCC		
33	I/O	67	I/O		
34	I/O				

FIGURE 2. Terminal connections - Continued.

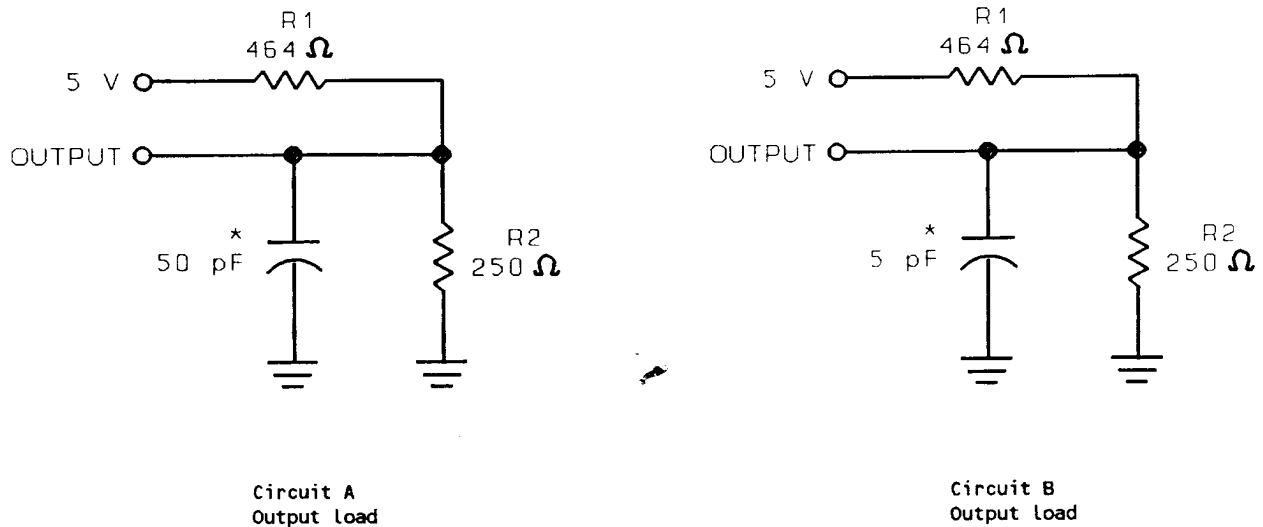
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Truth table		
Input pins		Output pins
I/CLK	I	I/O
X	X	Z

- NOTES:
 1. X = Don't care.
 2. Z = High impedance.

FIGURE 3. Truth table (unprogrammed).



*Including scope and jig (minimum values).

AC test conditions

Input pulse levels	GND to 3.0 V
Input rise and fall levels	≤ 6 ns
Input timing reference levels	1.5 V
Output reference levels	1.5 V

Input pulses

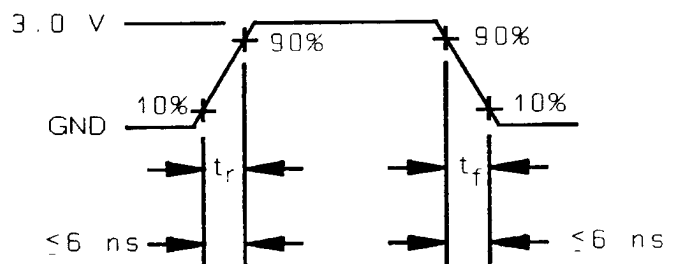
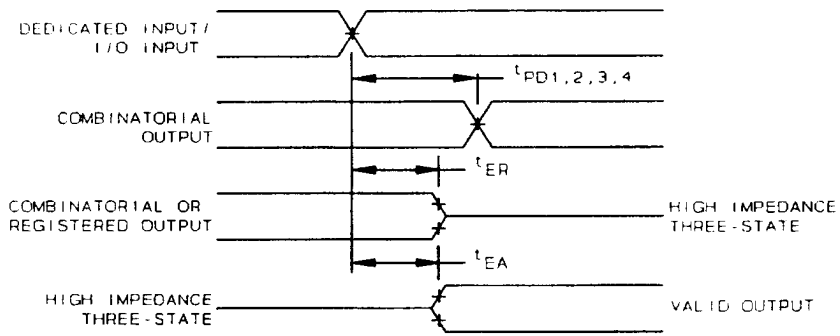


FIGURE 4. Output load circuits and test conditions.

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External combinational



External synchronous

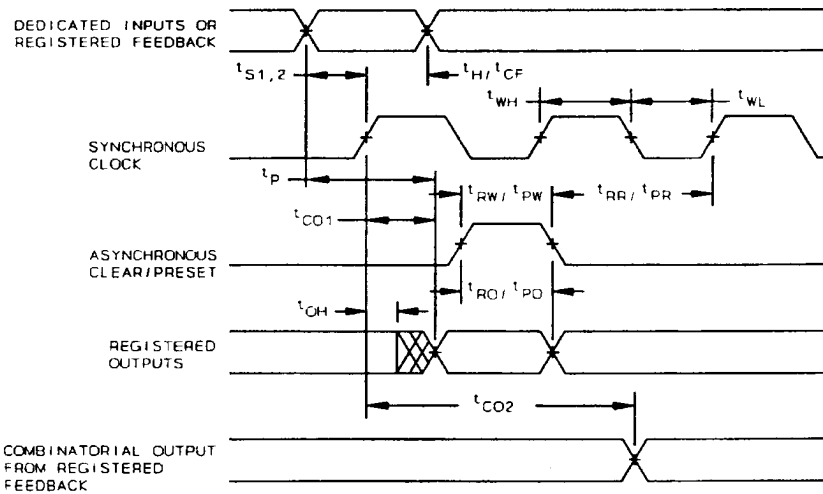


FIGURE 5. Switching waveforms.

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External asynchronous

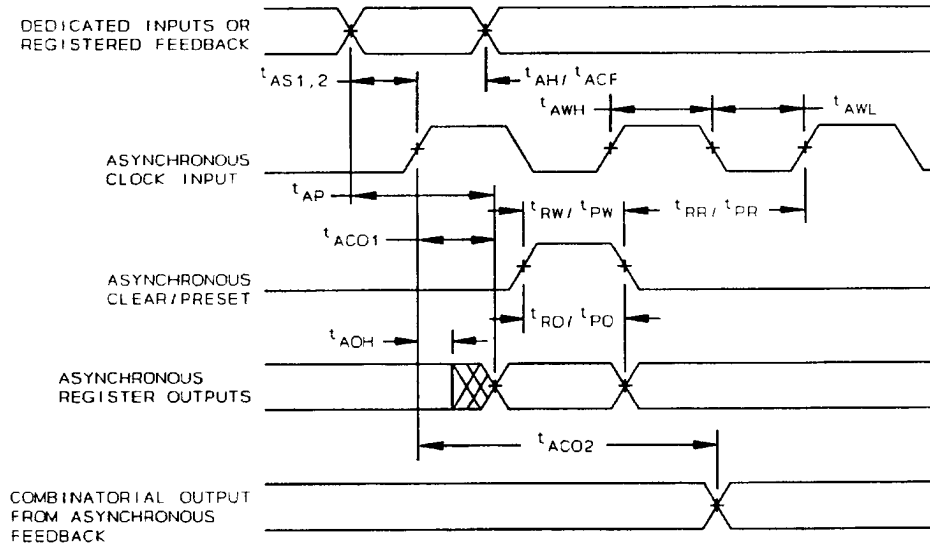


FIGURE 5. Switching waveforms - Continued.

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3.12.3 Verification of erasure or programmed EPLDs. When specified, devices shall be verified as either programmed (see 4.5) to the specified pattern or erased (see 3.6). As a minimum, verification shall consist of performing a functional test (subgroup 7) to verify that all bits are in the proper state. Any bit that does not verify to be in the proper state shall constitute a device failure, and shall be removed from the lot.

3.13 Endurance. A reprogrammability test shall be completed as part of the vendor's reliability monitor. This reprogrammability test shall be done only for initial characterization and after any design or process changes which may affect the reprogrammability of the device. The methods and procedures may be vendor specific, but will guarantee the number of program/erase endurance cycles listed in section 1.3 herein. The vendors procedure shall be under document control and shall be made available upon request.

3.14 Data retention. A data retention stress test shall be completed as part of the vendor's reliability process. This test shall be done initially and after any design or process change which may affect data retention. The methods and procedures may be vendor specific, but will guarantee the number of years listed in section 1.3 herein. The vendors procedure shall be under document control and shall be made available upon request. Data retention capability shall be guaranteed over the full military temperature range.

4. QUALITY ASSURANCE PROVISIONS

4.1 Sampling and inspection. For device class M, sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein). For device classes B and S, sampling and inspection procedures shall be in accordance with MIL-M-38510 and method 5005 of MIL-STD-883, except as modified herein. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-I-38535 and the device manufacturer's QM plan.

4.2 Screening. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. For device classes B and S, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to qualification and quality conformance inspection. For device classes Q and V, screening shall be in accordance with MIL-I-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection.

4.2.1 Additional criteria for device classes M, B, and S.

- a. Delete the sequence specified as initial (pre-burn-in) electrical parameters through interim (post-burn-in) electrical parameters of method 5004 and substitute lines 1 through 6 of table IIA herein.
- b. Prior to burn-in, the devices shall be programmed (see 4.5 herein) with a checkerboard pattern or equivalent (manufacturers at their option may employ an equivalent pattern provided it is a topologically true alternating bit pattern). The pattern shall be read before and after burn-in. Devices having bits not in the proper state after burn-in shall constitute a device failure and shall be included in the PDA calculation and shall be removed from the lot (see 4.2.3 herein). The manufacturer as an option may use built-in test circuitry by testing the entire lot to verify programmability and AC performance without programming the user array.
- c. For device class M, the test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. For device classes B and S, the test circuit shall be submitted to the qualifying activity. For device classes M, B, and S, the test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015.

(1) Static burn-in for device class S (method 1015 of MIL-STD-883, test condition A).

- (a) All inputs shall be connected to GND. Outputs may be open or connected to 4.5 V minimum. Resistors R1 are optional on both inputs and outputs, and required on outputs connected to $V_{CC} \pm 0.5$ V. $R1 = 220$ ohms to 47 kohms. For static II burn-in, reverse all input connections (i.e., V_{SS} to V_{CC}).
- (b) $V_{CC} = 4.5$ V minimum.
- (c) Ambient temperature (T_A) shall be +125°C minimum.
- (d) Test duration for the static test shall be 48 hours minimum. The 48-hour burn-in shall be broken into two sequences of 24 hours each (Static I and Static II) followed by interim electrical measurements.

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(2) Dynamic burn-in for device classes M, B, and S (method 1015 of MIL-STD-883, test condition D; for circuit, see 4.2.1b herein).

(a) Static burn-in for device class M (method 1015 of MIL-STD-883, test condition C; for circuit, see 4.2.1c herein) may be done in lieu of dynamic burn-in.

d. Interim and final electrical parameters shall be as specified in table IIA herein.

e. For class S and B devices, post dynamic burn-in electrical parameter measurements may, at the manufacturer's option, be performed separately or included in the final electrical parameter requirements.

f. A data retention stress test shall be included as part of the screening procedure and shall consist of the following steps: (Steps 1 through 4 may be performed at the wafer level. Failures shall be removed from the lot. The maximum storage temperature shall not exceed +200°C for packaged devices or +300°C for unassmbled devices.) If steps 1 through 4 are not done at wafer level, then a sample of 116 devices shall be selected to accomplish this test with the pass criteria of no failures.

Margin test method. *Steps 1 through 4 may be performed at wafer level.

(1) Program a minimum or 95 percent of the total number of cells, including the slowest programming cell (see 3.12.2).

(2) Bake, unbiased, for 72 hours at +140°C or for 32 hours at +150°C or for 8 hours at +200°C or for 2 hours at +300°C for unassembled devices only.

(3) Perform electrical test (see 4.2.1b) at +25°C including a margin test at $V_m = +5.7$ V and loose timing (i.e., 1 μ s).

(4) Erase (see 3.12.1).

(5) Verify erasure (see 3.12.3).

4.2.2 Additional criteria for device classes Q and V.

a. The burn-in test duration, test condition, and test temperature or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-I-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-I-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015.

b. Interim and final electrical test parameters shall be as specified in table IIA herein.

c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in appendix B of MIL-I-38535.

d. Additional requirements beyond MIL-I-38535 for classes Q and V are specified in table IIA herein.

4.2.3 Percent defective allowable (PDA).

a. The PDA for class S devices shall be 5 percent for static burn-in and 5 percent for dynamic burn-in, based on the exact number of devices submitted to each separate burn-in.

b. The PDA for class B devices shall be in accordance with MIL-M-38510 for dynamic burn-in.

c. Static burn-in I and II failures shall be cumulative for determining PDA.

d. Those devices whose measured characteristics, after burn-in, exceed the specified delta limits or electrical parameter limits specified in table I, subgroup 1, are defective and shall be removed from the lot. The verified failures divided by the total number of devices in the lot initially submitted to burn-in shall be used to determine the percent defective for the lot and the lot shall be accepted or rejected based on the specified PDA.

e. The PDA for device classes Q and V shall be in accordance with MIL-I-38535 for dynamic burn-in.

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4.3 Qualification inspection.

4.3.1 Qualification inspection for device classes B and S. Qualification inspection for device classes B and S shall be in accordance with MIL-M-38510. Inspections to be performed shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.5). Qualification data for subgroups 7, 8A, and 8B shall be attributes only.

4.3.1.1 Qualification extension for device class B and S. When authorized by the qualifying activity, if a manufacturer qualifies one device type which is identical (i.e., same die), to other device types on this drawing, the slower device types may be part I qualified, upon the request of the manufacturer, without any further testing. The faster device types may be part I qualified by performing only group A qualification testing.

4.3.2 Qualification inspection for device classes Q and V. Qualification inspection for device classes Q and V shall be in accordance with MIL-I-38535. Inspections to be performed shall be those specified in MIL-I-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.5).

4.4 Conformance inspection. Quality conformance inspection for device class M shall be in accordance with MIL-STD-883 (see 3.1 herein) and as specified herein. Quality conformance inspection for device classes B and S shall be in accordance with MIL-M-38510 and as specified herein. Inspections to be performed for device classes M, B, and S shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.5). Technology conformance inspection for classes Q and V shall be in accordance with MIL-I-38535 including groups A, B, C, D, and E inspections and as specified herein.

4.4.1 Group A inspection.

- a. Tests shall be as specified in table IIA herein.
- b. Subgroups 5 and 6 of table I method 5005 of MIL-STD-883 shall be omitted.
- c. For device class M, subgroups 7 and 8 tests shall be sufficient to verify the truth table. For device classes B and S, subgroups 7 and 8 tests shall be sufficient to verify the truth table as approved by the qualifying activity. For device classes Q and V, subgroups 7 and 8 shall include verifying the functionality of the device, these tests shall have been fault graded in accordance with MIL-STD-883, test method 5012 (see 1.5 herein).
- d. Devices shall be tested for programmability and ac performance compliance to the requirements of Group A, subgroups 9, 10, and 11. Either of two techniques is acceptable:
 - (1) Testing the lot using additional built-in test circuitry which allows the manufacturer to verify programmability and ac performance without programming the user array. If this is done, the resulting test patterns shall be verified on all devices during subgroups 9, 10, and 11, group A testing per the sampling plan specified in MIL-STD-883, method 5005.
 - (2) If such compliance cannot be tested on an unprogrammed device, a sample shall be selected to satisfy programmability requirements prior to performing subgroups 9, 10, and 11. Twelve devices shall be submitted to programming (see 3.2.4.1). If more than one device fails to program, the lot shall be rejected. At the manufacturers option, the sample may be increased to 24 total devices with no more than two total device failures allowable. Ten devices from the programmability sample shall be submitted to the requirements of group A, subgroup 9, 10, and 11. If more than two devices fail, the lot shall be rejected. At the manufacturer's option, the sample may be increased to 20 total devices with no more than four total device failures allowable. After completion of all testing, the devices shall be erased and verified except devices submitted to groups C and D testing.
- e. O/V (latch-up) tests shall be measured only for initial qualification and after any design or process changes which may affect the performance of the device. For device class M procedures and circuits shall be maintained under document revision level control by the manufacturer and shall be made available to the preparing activity or acquiring activity upon request. For device classes B and S, the procedures and circuits shall be maintained under document revision control by the manufacturer and shall be made available to the qualifying activity upon request. For device classes Q and V, procedures and circuits shall be under the control of the device manufacturer's technical review board (TRB) in accordance with MIL-I-38535 and shall be made available to the preparing activity or acquiring activity upon request. Testing shall be on all pins, on five devices with zero failures. Latch-up test shall be considered destructive. Information contained in JEDEC standard number 17 may be used for reference.

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f. Subgroup 4 (C_{IN} and C_{OUT} measurements) shall be measured only for initial qualification and after any process or design changes which may affect input or output capacitance. Capacitance shall be measured between the designated terminal and GND at a frequency of 1 MHz. Sample size is 15 devices with no failures, and all input and output terminals tested.

4.4.2 Group B inspection. The group B inspection end-point electrical parameters shall be as specified in table IIA herein. For device class S steady-state life tests, the test circuit shall be submitted to the qualifying activity.

- a. For device class S steady-state life test shall be conducted using test condition D and the circuit described in 4.2.1c herein, or equivalent as approved by the qualifying activity.
- b. For device class S only, end-point electrical parameters shall be as specified in table IIA herein. Delta limits shall apply only to subgroup 5 of group B inspections and shall consist of tests specified in table IIB herein.
- c. All devices selected for class S electrical testing shall be programmed (see 3.2.4.1 herein). After completion of all testing the devices shall be erased and verified (except devices submitted to groups C and D).

4.4.3 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table IIA herein. Delta limits shall apply only to subgroup 1 of group C inspections and shall consist of tests specified in table IIB herein.

4.4.3.1 Additional criteria for device classes M and B. Steady-state life test conditions, method 1005 of MIL-STD-883:

- a. The devices selected for testing shall be programmed (see 3.2.4.1 herein). After completion of all testing the devices shall be erased and verified (except devices submitted to group D).
- b. Test condition D. For device class M, the test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. For device class B, the test circuit shall be submitted to the qualifying activity. For device classes M and B, the test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005.
- c. $T_A = +125^\circ\text{C}$, minimum.
- d. Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

4.4.3.2 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-I-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-I-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005. After the completion of all testing, the devices shall be erased and verified prior to delivery.

4.4.4 Group D inspection. For group D inspection end-point electrical parameters shall be as specified in table IIA herein. The devices selected for testing shall be programmed (see 3.2.4.1 herein). After completion of all testing, the devices shall be erased and verified.

4.4.5 Group E inspection. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein). RHA levels for device classes B, S, Q, and V shall be M, D, R, and H and for device class M shall be M and D.

- a. End-point electrical parameters shall be as specified in table IIA herein.
- b. For device classes M, B, and S, the devices shall be subjected to radiation hardness assured tests as specified in MIL-M-38510 for the RHA level being tested. For device classes Q and V, the devices or test vehicle shall be subjected to radiation hardness assured tests as specified in MIL-I-38535 for the RHA level being tested. All device classes must meet the postirradiation end-point electrical parameter limits as defined in table I at $T_A = +25^\circ\text{C} \pm 5^\circ\text{C}$, after exposure, to the subgroups specified in table IIA herein.
- c. When specified in the purchase order or contract, a copy of the RHA delta limits shall be supplied.

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TABLE IIA. Electrical test requirements. 1/ 2/ 3/ 4/ 5/ 6/ 7/

Line no.	Test requirements	Subgroups (per method 5005, table I)			Subgroups (per MIL-I-38535, table III)	
		Device class M	Device class B	Device class S	Device class Q	Device class V
1	Interim electrical parameters (see 4.2)		1,7,9 or 2,8A,10	1,7,9 or 2,8A,10		1,7,9 or 2,8A,10
2	Static burn-in (method 1015)	Not required	Not required	Required	Not required	Required
3	Same as line 1			1* Δ		1* Δ
4	Dynamic burn-in (method 1015)	Required	Required	Required	Required	Required
5	Same as line 1			7* Δ		7* Δ
6	Final electrical test parameters for unprogrammed devices	1*,2,3,7*,8A,8B	1*,2,3,7*,8A,8B	1*,2,3,7*,8A,8B	1*,2,3,7*,8A,8B	1*,2,3,7*,8A,8B
6a	Final electrical test parameters for programmed devices	1*,2,3,7*,8A,8B,9	1*,2,3,7*,8A,8B,9	1*,2,3,7*,8A,8B,9	1*,2,3,7*,8A,8B,9	1*,2,3,7*,8A,8B,9
7	Group A test requirements	1,2,3,4**,7,8A,8B,9,10,11	1,2,3,4**,7,8A,8B,9,10,11	1,2,3,4**,7,8A,8B,9,10,11	1,2,3,4**,7,8A,8B,9,10,11	1,2,3,4**,7,8A,8B,9,10,11
8	Group B end-point electrical parameters			1,2,3,7,8A,8B,9,10,11 Δ		
9	Group C end-point electrical parameters	2,3,7,8A,8B	1,2,3,7,8A,8B Δ		1,2,3,7,8A,8B Δ	1,2,3,7,8A,8B,9,10,11 Δ
10	Group D end-point electrical parameters	2,3,7,8A,8B	2,3,7,8A,8B	2,3,7,8A,8B	2,3,7,8A,8B	2,3,7,8A,8B
11	Group E end-point electrical parameters	1,7,9	1,7,9	1,7,9	1,7,9	1,7,9

- 1/ Blank spaces indicate tests are not applicable.
- 2/ Any or all subgroups may be combined when using high-speed testers.
- 3/ Subgroups 7 and 8 functional tests shall verify the truth table.
- 4/ * indicates PDA applies to subgroups 1 and 7.
- 5/ ** see 4.4.1f.
- 6/ see 4.4.1e.
- 7/ Δ indicates delta limit (see table IIB) shall be required where specified, and the delta values shall be computed with reference to the previous interim electrical parameters (line 1).

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TABLE IIB. Delta Limits at +25°C.

Parameter <u>1/</u>	Device types
	All
I _{CC2}	±40 mA of specified value in table I
I _{IX}	±1.0 μA of specified value in table I

1/ The above parameter shall be recorded before and after the required burn-in and life tests to determine the delta.

4.5 Programming procedure. The programming procedures shall be as specified by the device manufacturer and shall be made available upon request.

4.6 Erasing procedures. The recommended erasure procedure is exposure to shortwave ultraviolet light which has a wavelength of 2537 angstroms (Å). The integrated dose (i.e., ultraviolet intensity x exposure time) for erasure should be a minimum of fifteen (15) Ws/cm². The erasure time with this dosage is approximately 15 to 20 minutes using an ultraviolet lamp with a 1200 μW/cm² power rating. The device should be placed within one inch of the lamp tubes during erasure. The maximum integrated dose the device can be exposed to without damage is 7258 Ws/cm² (1 week at 12,000 μW/cm²). Exposure of the device to high intensity ultraviolet light for long periods may cause permanent damage.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510 for device classes M, B, and S and MIL-I-38535 for device classes Q and V.

6. NOTES

(This section contains information of a general or explanatory nature that may be helpful, but is not mandatory.)

6.1 Intended use. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.

6.1.1 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.

6.1.2 Substitutability. Device classes B and Q devices will replace device class M devices.

6.2 Configuration control of SMD's. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished in accordance with MIL-STD-481 using DD Form 1693, Engineering Change Proposal (Short Form).

6.3 Record of users. Military and industrial users shall inform Defense Electronics Supply Center when a system application requires configuration control and which SMD's are applicable to that system. DESC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DESC-EC, telephone (513) 296-6047.

6.4 Comments. Comments on this drawing should be directed to DESC-EC, Dayton, Ohio 45444, or telephone (513) 296-5377.

6.5 Symbols, definitions, and functional descriptions.

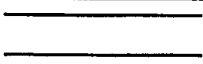


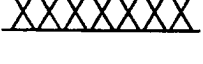
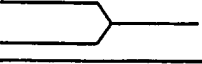
- C_{IN}/C_{OUT} Input/Output terminal capacitance.
- V_{SS} Ground zero voltage potential.
- I_{CC} Supply current.
- I_{IX} Input current.
- I_{OZ} Output current.
- T_C Case temperature.
- V_{CC} Positive supply voltage (5.0 V).

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6.5.1 Timing Limits. The table of timing values shows either a minimum or a maximum limit for each parameter. Input requirements are specified from the external system point of view. Thus, address setup time is shown as a minimum since the system must supply at least that much time (even though most devices do not require it). On the other hand, responses from the memory are specified from the device point of view. Thus, the access time is shown as a maximum since the device never provides data later than that time.

6.5.2 Waveforms.

Waveform symbol	Input	Output
	MUST BE VALID	WILL BE VALID
	CHANGE FROM H TO L	WILL CHANGE FROM H TO L
	CHANGE FROM L TO H	WILL CHANGE FROM L TO H
	DON'T CARE ANY CHANGE PERMITTED	CHANGING STATE UNKNOWN
		HIGH IMPEDANCE

6.6 One part - one part number system. The one part - one part number system described below has been developed to allow for transitions between identical generic devices covered by the four major microcircuit requirements documents (MIL-M-38510, MIL-H-38534, MIL-I-38535, and 1.2.1 of MIL-STD-883) without the necessity for the generation of unique PIN's. The four military requirements documents represent different class levels, and previously when a device manufacturer upgraded military product from one class level to another, the benefits of the upgraded product were unavailable to the Original Equipment Manufacturer (OEM), who was contractually locked into the original unique PIN. By establishing a one part number system covering all four documents, the OEM can procure to the highest class level available for a given generic device to meet system needs without modifying the original contract parts selection criteria.

<u>Military documentation format</u>	<u>Example PIN under new system</u>	<u>Manufacturing source listing</u>	<u>Document Listing</u>
New MIL-M-38510 Military Detail Specifications (in the SMD format)	5962-XXXXZZ(B or S)YY	QPL-38510 (Part 1 or 2)	MIL-BUL-103
New MIL-H-38534 Standardized Military Drawings	5962-XXXXZZ(H or K)YY	QML-38534	MIL-BUL-103
New MIL-I-38535 Standardized Military Drawings	5962-XXXXZZ(Q or V)YY	QML-38535	MIL-BUL-103
New 1.2.1 of MIL-STD-883 Standardized Military Drawings	5962-XXXXZZ(M)YY	MIL-BUL-103	MIL-BUL-103

6.7 Sources of supply.

6.7.1 Sources of supply for device classes B and S. Sources of supply for device classes B and S are listed in QPL-38510.

6.7.2 Sources of supply for device classes Q and V. Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DESC-EC and have agreed to this drawing.

6.7.3 Approved sources of supply for device class M. Approved sources of supply for class M are listed in MIL-BUL-103. The vendors listed in MIL-BUL-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DESC-EC.

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